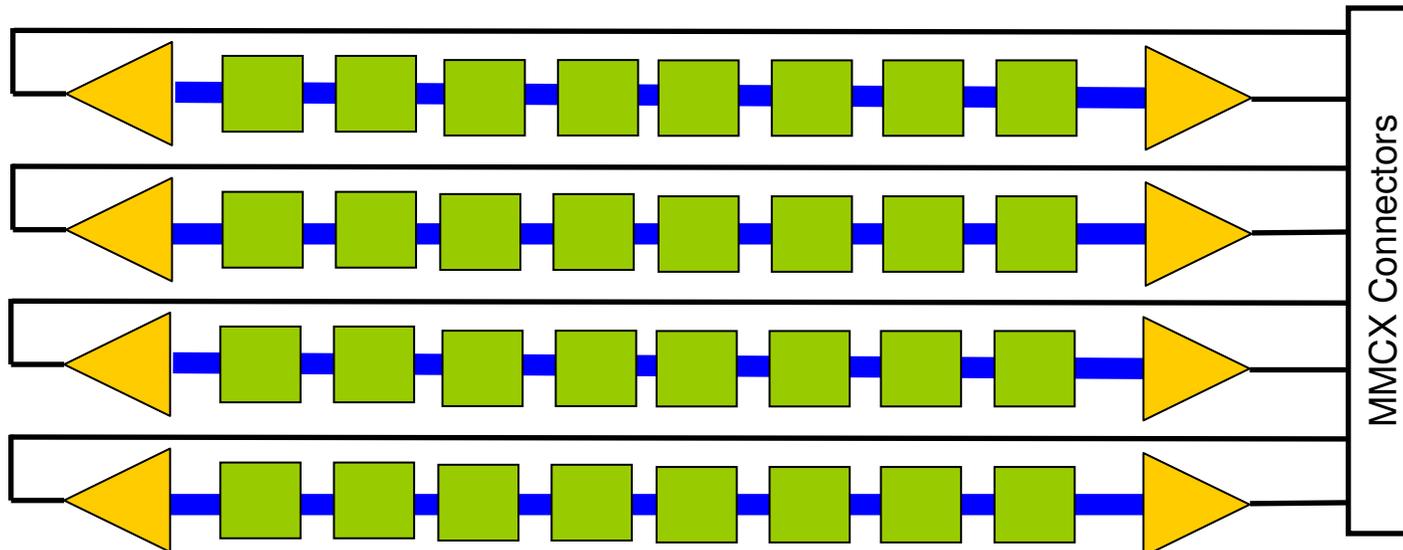


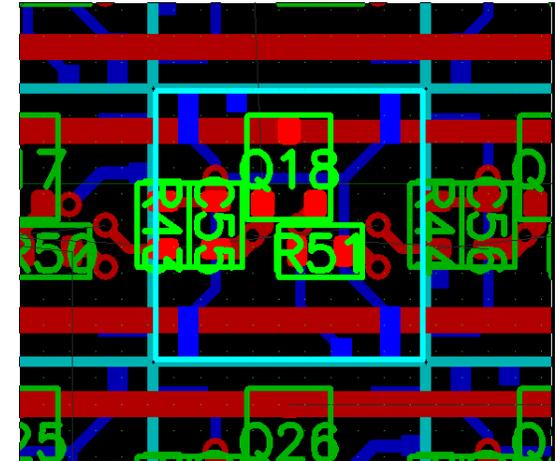
PET-TOF Strip Line Status

- Next SL prototype has 4 strings of 8xSiPMs
 - Design is for **STM 10-contact 5.1x5.1 mm²** package
 - Diode pitch is **5.2 mm**
- Boards should arrive any time now, full component kit exists
 - First I plan to assemble 2 boards with a single line of diodes (solder)
 - Second step is to assemble a complete board, using anisotropic conductive film (will need 4x8 scintillator blocks for that – to push diodes against the board)
 - If conductive film does not work – will solder everything, and we have to learn how to ensure a good optical contact between scintillator and diodes

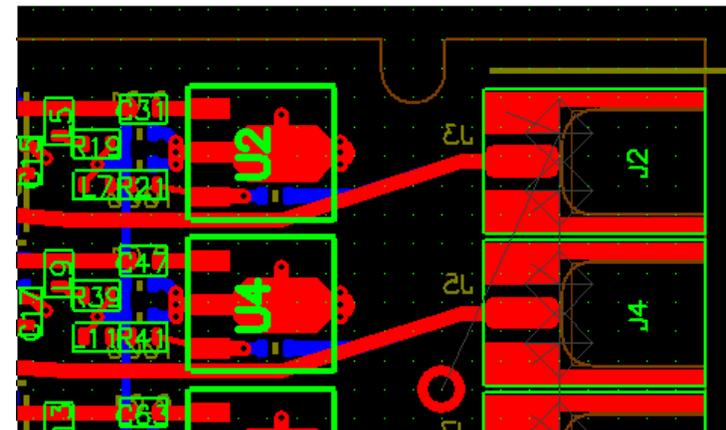
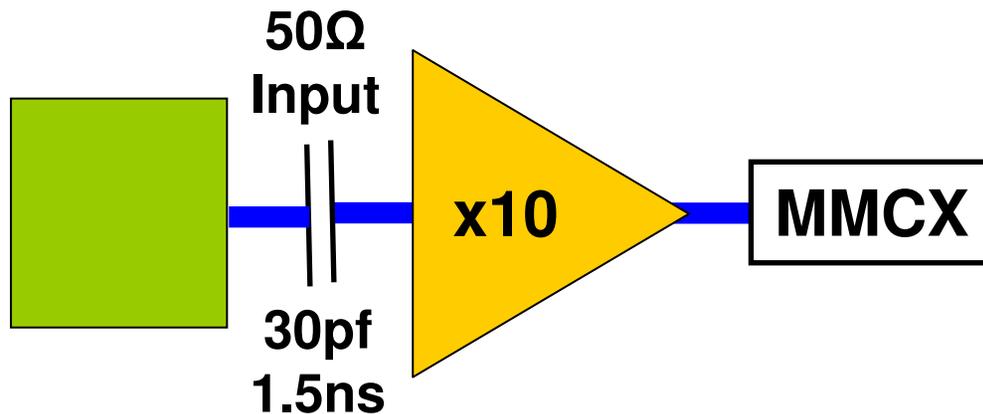


Strip Line Details

- Next SL prototype will have 4 strings of 8xSiPMs
 - Design is for **STM 10-contact 5.1x5.1 mm²** package (that is a rather challenging package for board layout)
 - Diode pitch is **5.2 mm**
- I have a layout of an elementary cell, note two strip lines per row, the second one returns far end signal to the “digital end” of the board
 - **GALI-S66+** amplifier from MiniCircuits (not an ideal package, but layout is possible) relatively low power consumption **16mA@6V**, gain of **x10@1GHz / x6.6@3GHz**)



Diode cell layout

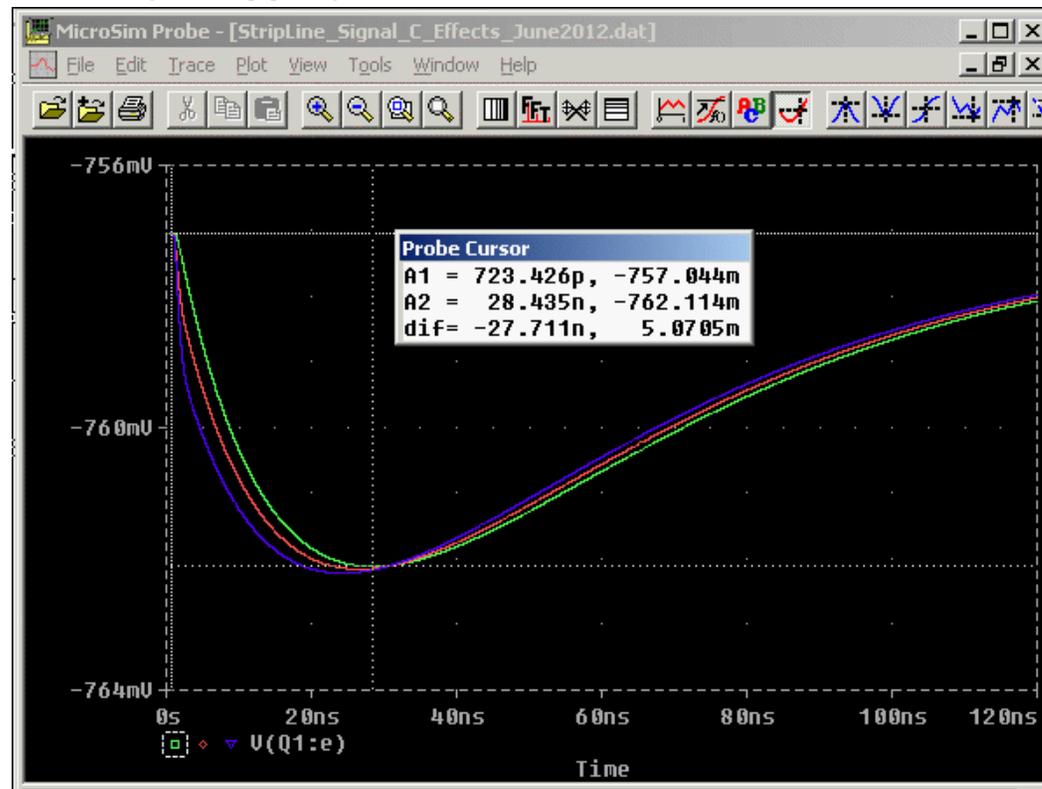


Amplifier cell layout

Signal Shape Simulations

- I have run a series of Spice simulations to get an idea of the pulse shape, and amplitude for various scenarios of diode interfacing, and pulse shaping
 - Light pulse shape:
 - 0.3ns rise time
 - 40ns fall time (LYSO time constant) -
 - Assumed 20ns of SiPM recovery time LYSO light yield is 500 pe, and SiPM gain of $\times 10^6$ (easy to scale if different)
 - For shaping a simple C-R differentiating (“clipping”) circuit is used with time constant of the order of 1ns

SiPM output pulse shape for different pixel stray capacitance:
0.1%(green) 10%(red) 20%(blue)

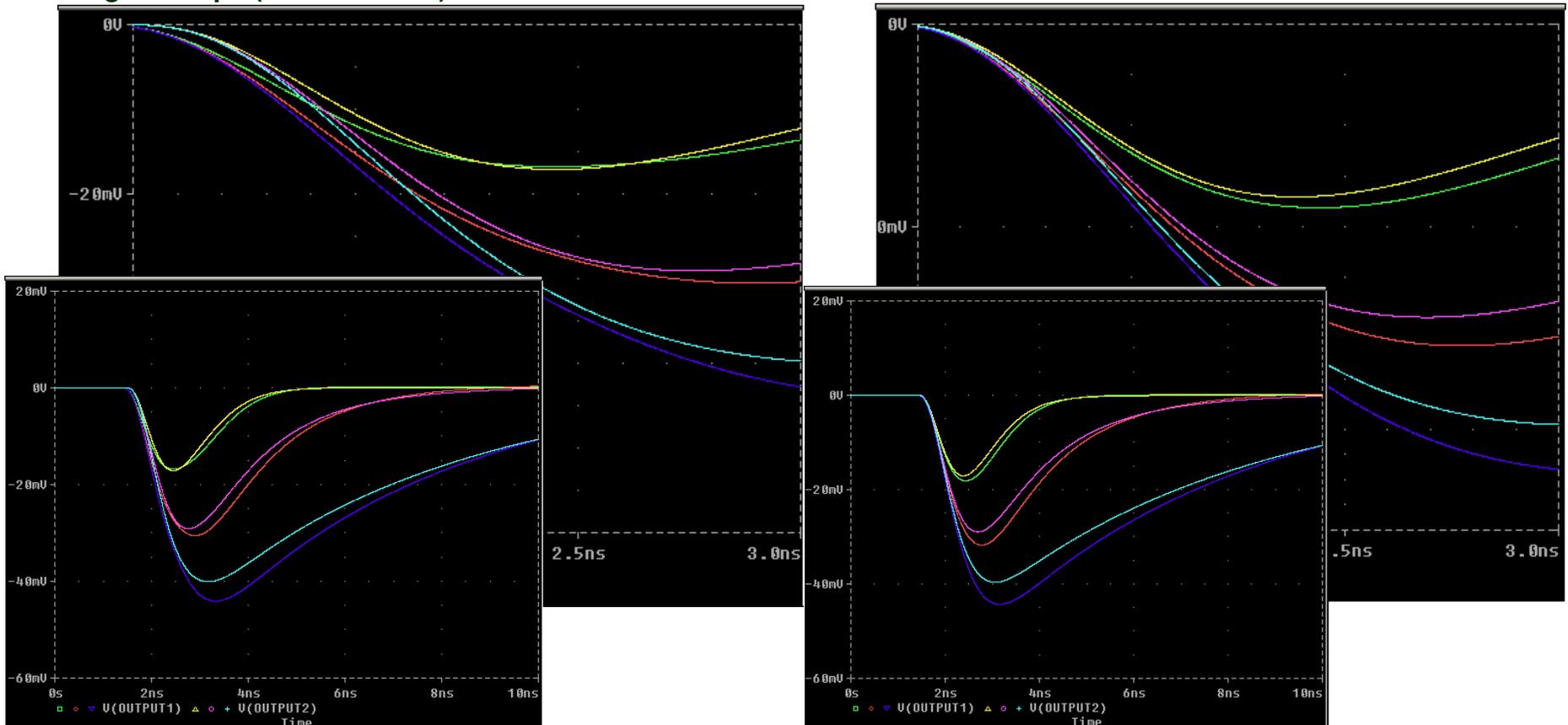


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Output Signals (after x10 amplifier and shaping)

- Signals shown at the two ends of the same transmission line (aligned in time):
 - Output 1 – near end
 - Output 2 – far end (lower peak amplitude)
- Pulse shapes are shown for different output capacitances of the SiPM buffer transistors:
 - Left - 0.5pf (previous SL board)
 - Right - 0.1pf (new SL board)



SiPM output pulse shape for different shaping capacitors: 10/30/100pf

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